

COMPLEMENTARY SILICON POWER TRANSISTORS

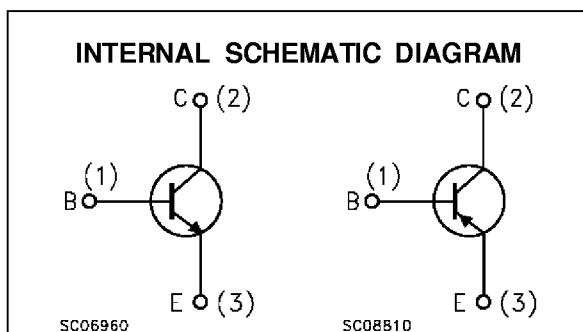
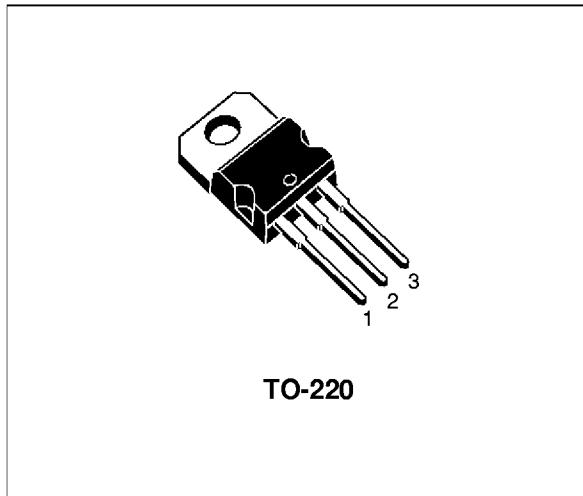
- BD243B, BF243C, BD244B AND DB244C ARE SGS-THOMSON PREFERRED SALES TYPES

DESCRIPTION

The BD243A, BD243B and BD243C are silicon epitaxial-base NPN transistors mounted in Jedec TO-220 plastic package.

They are intended for use in medium power linear and switching applications.

The complementary PNP types are BD244A, BD244B and BD244C respectively.



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | | | | Unit |
|------------------|--|--------|------------|--------|--------|------|
| | | NPN | BD243A | BD243B | BD243C | |
| PNP | BD244A | BD244B | BD244C | | | |
| V _{CBO} | Collector-Base Voltage ($I_E = 0$) | 60 | 80 | 100 | | V |
| V _{CBO} | Collector-Emitter Voltage ($I_B = 0$) | 60 | 80 | 100 | | V |
| V _{EBO} | Emitter-Base Voltage ($I_C = 0$) | | 5 | | | V |
| I _C | Collector Current | | 6 | | | A |
| I _{CM} | Collector Peak Current | | 10 | | | A |
| I _B | Base Current | | 2 | | | A |
| P _{tot} | Total Dissipation at $T_c \leq 25^\circ\text{C}$ | | 65 | | | W |
| T _{stg} | Storage Temperature | | -65 to 150 | | | °C |
| T _j | Max. Operating Junction Temperature | | 150 | | | °C |

For PNP types voltage and current values are negative.

BD243A/B/C/BD244A/B/C

THERMAL DATA

| | | | | |
|-----------------------|-------------------------------------|-----|------|------|
| R _{thj-case} | Thermal Resistance Junction-case | Max | 1.92 | °C/W |
| R _{thj-amb} | Thermal Resistance Junction-ambient | Max | 62.5 | °C/W |

ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ °C unless otherwise specified)

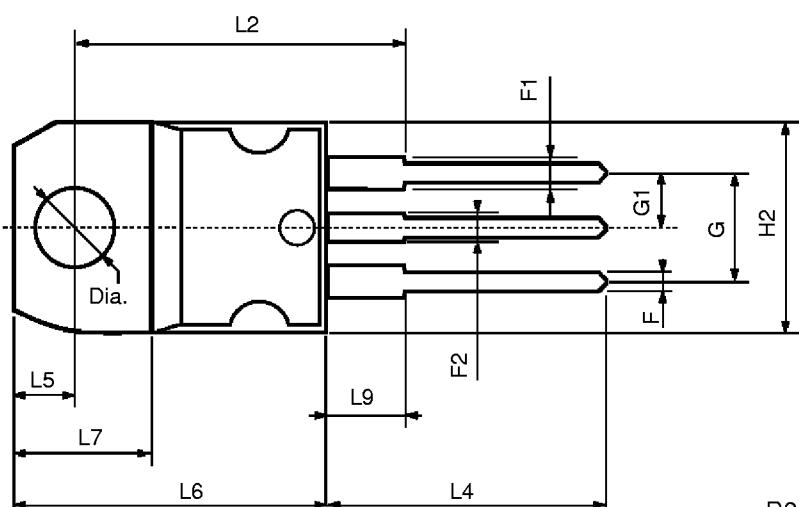
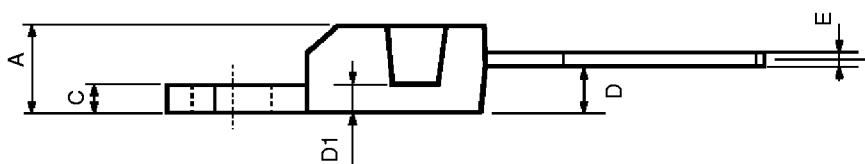
| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------------|--|--|-----------------|------|------|------|
| I _{CES} | Collector Cut-off Current ($V_{BE} = 0$) | $V_{CE} = \text{rated}$ V_{CEO} | | | 0.4 | mA |
| I _{CEO} | Collector Cut-off Current ($I_B = 0$) | for BD243A/BD244A $V_{CE} = 30$ V for BD243B/BD244B $V_{CE} = 60$ V for BD243C/BD244C $V_{CE} = 60$ V | | | 0.7 | mA |
| I _{EBO} | Emitter Cut-off Current ($I_C = 0$) | $V_{EB} = 5$ V | | | 1 | mA |
| V _{CEO(sus)*} | Collector-Emitter Sustaining Voltage | I _C = 30 mA for BD243A/BD244A for BD243B/BD244B for BD243C/BD244C | 60 80 100 | | | V |
| V _{CE(sat)*} | Collector-Emitter Saturation Voltage | I _C = 6 A I _B = 1 mA | | | 1.5 | V |
| V _{BE*} | Base-Emitter Voltage | I _C = 6 A V _{CE} = 4 V | | | 2 | V |
| h _{FE*} | DC Current Gain | I _C = 0.3 A V _{CE} = 4 V I _C = 3 A V _{CE} = 4 V | 30 15 | | 150 | |
| h _{fe} | Small Signal Current Gain | I _C = 0.5 A V _{CE} = 10 V f = 1MHz I _C = 0.5 A V _{CE} = 10 V f = 1KHz | 3 20 | | | |

* Pulsed: Pulse duration = 300 µs, duty cycle ≤ 2 %

For PNP types voltage and current values are negative.

TO-220 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|-------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| C | 1.23 | | 1.32 | 0.048 | | 0.051 |
| D | 2.40 | | 2.72 | 0.094 | | 0.107 |
| D1 | | 1.27 | | | 0.050 | |
| E | 0.49 | | 0.70 | 0.019 | | 0.027 |
| F | 0.61 | | 0.88 | 0.024 | | 0.034 |
| F1 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| F2 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| G | 4.95 | | 5.15 | 0.194 | | 0.203 |
| G1 | 2.4 | | 2.7 | 0.094 | | 0.106 |
| H2 | 10.0 | | 10.40 | 0.393 | | 0.409 |
| L2 | | 16.4 | | | 0.645 | |
| L4 | 13.0 | | 14.0 | 0.511 | | 0.551 |
| L5 | 2.65 | | 2.95 | 0.104 | | 0.116 |
| L6 | 15.25 | | 15.75 | 0.600 | | 0.620 |
| L7 | 6.2 | | 6.6 | 0.244 | | 0.260 |
| L9 | 3.5 | | 3.93 | 0.137 | | 0.154 |
| DIA. | 3.75 | | 3.85 | 0.147 | | 0.151 |



P011C

BD243A/B/C/BD244A/B/C

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